

#### **Low Drop Voltage Regulator**

**TLE 4274** 



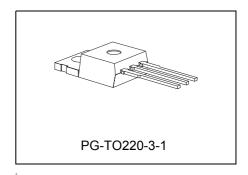


#### **Features**

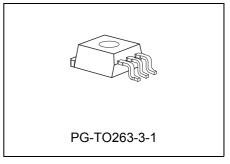
- Output voltage 5 V, 8.5 V or 10 V
- Output voltage tolerance ≤ ±4%
- Current capability 400 mA
- Low-drop voltage
- Very low current consumption
- Short-circuit proof
- Reverse polarity proof
- Suitable for use in automotive electronics
- Green Product (RoHS compliant) version of TLE 4274
- AEC qualified

#### **Functional Description**

The TLE 4274 is a low drop voltage regulator available in a TO220, TO252 and TO263 package. The IC regulates an input voltage up to 40 V to  $V_{\rm Qrated}$  = 5.0 V (V50), 8.5 V (V85) and 10 V (V10). The maximum output current is 400 mA. The IC is short-circuit proof and incorporates temperature protection that disables the IC at overtemperature. A 3.3 V and 2.5 V version is also available. For information about the low output voltage types please refer to the data sheet TLE 4274 / 3.3 V; 2.5 V.







Туре	Package
TLE 4274 V10	PG-TO220-3-1 (RoHS compliant)
TLE 4274 V50	PG-TO220-3-1 (RoHS compliant)
TLE 4274 V85	PG-TO220-3-1 (RoHS compliant)
TLE 4274 DV50	PG-TO252-3-11 (RoHS compliant)
TLE 4274 GV10	PG-TO263-3-1 (RoHS compliant)
TLE 4274 GV50	PG-TO263-3-1 (RoHS compliant)
TLE 4274 GV85	PG-TO263-3-1 (RoHS compliant)



#### **Dimensioning Information on External Components**

The input capacitor  $C_{\rm I}$  is necessary for compensating line influences. Using a resistor of approx. 1  $\Omega$  in series with  $C_{\rm I}$ , the oscillating of input inductivity and input capacitance can be damped. The output capacitor  $C_{\rm Q}$  is necessary for the stability of the regulation circuit. Stability is guaranteed at values  $C_{\rm Q} \ge 22~\mu{\rm F}$  and an ESR of  $\le 3~\Omega$  within the operating temperature range.

#### **Circuit Description**

The control amplifier compares a reference voltage to a voltage that is proportional to the output voltage and drives the base of the series transistor via a buffer. Saturation control as a function of the load current prevents any oversaturation of the power element. The IC also includes a number of internal circuits for protection against:

- Overload
- Overtemperature
- Reverse polarity



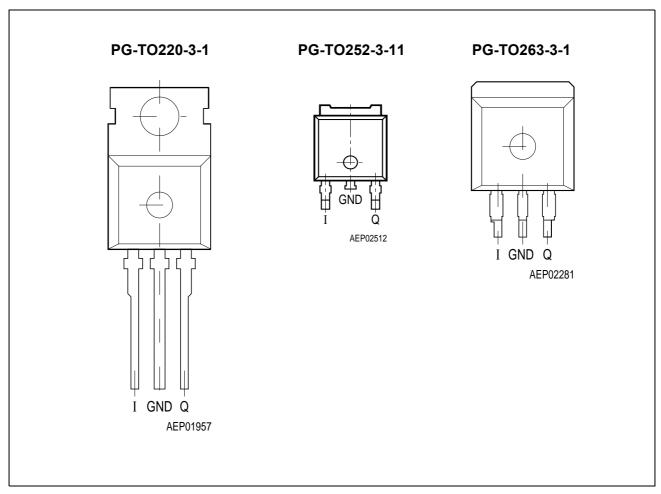


Figure 1 Pin Configuration (top view)

Table 1 Pin Definitions and Functions

Pin No.	Symbol	Function
1	I	Input; block to ground directly at the IC with a ceramic capacitor.
2	GND	Ground
3	Q	<b>Output;</b> block to ground with a $\geq$ 22 $\mu$ F capacitor, ESR $\leq$ 3 $\Omega$ .

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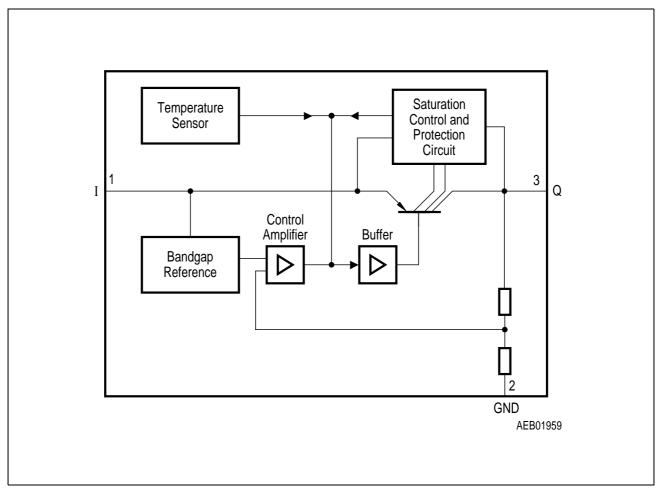


Figure 2 Block Diagram



Table 2 Absolute Maximum Ratings

 $T_{\rm i}$  = -40 to 150 °C

Parameter	Symbol	Limit Values		Unit	Test Condition
		Min.	Max.		
Input				•	
Voltage	$V_1$	-42	45	V	_
Current	$I_{I}$	_	_	_	Internally limited
Output	·	-		•	
Voltage	$V_{Q}$	-1.0	40	V	_
Current	$I_{Q}$	_	_	_	Internally limited
Ground	<u> </u>	-		•	
Current	$I_{GND}$	_	100	mA	_
Temperature	<u> </u>	-		•	
Junction temperature	$T_{j}$	_	150	°C	_
Storage temperature	$T_{stg}$	-50	150	°C	_

Note: Maximum ratings are absolute ratings; exceeding any one of these values may cause irreversible damage to the integrated circuit.

**Table 3** Operating Range

Parameter	Symbol	Symbol Limit Values		Unit	Remarks
		Min.	Max.		
Input voltage; V50, DV50, GV50	$V_1$	5.5	40	V	-
Input voltage, V85, GV85	$V_1$	9.0	40	V	_
Input voltage, V10, GV10	$V_1$	10.5	40	V	_
Junction temperature	$T_{\rm j}$	-40	150	°C	_
Thermal Resistance	-	•		•	
Junction ambient	$R_{thja}$	_	65	K/W	TO220 <sup>1)</sup>
Junction ambient	$R_{thja}$	_	78	K/W	TO252 <sup>1)</sup>
Junction ambient	$R_{thja}$	_	52	K/W	TO263 <sup>1)</sup>
	$R_{thjc}$	_	4	K/W	_

<sup>1)</sup> Worst case; regarding peak temperature, zero airflow mounted on PCB  $80 \times 80 \times 1.5 \text{ mm}^3$ ,  $300 \text{ mm}^2$  heat sink area.

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Table 4 Characteristics

 $V_{\rm I}$  = 13.5 V; -40  $^{\circ}{\rm C}$  <  $T_{\rm j}$  < 150  $^{\circ}{\rm C}$  (unless otherwise specified)

Parameter	Symbol	Limit Values			Unit	<b>Measuring Conditions</b>
		Min.	Тур.	Max.		
Output voltage V50-Version	$V_{Q}$	4.8	5	5.2	V	$5 \text{ mA} < I_{\text{Q}} < 400 \text{ mA}$ $6 \text{ V} < V_{\text{I}} < 28 \text{ V}$
Output voltage V50-Version	$V_{Q}$	4.8	5	5.2	V	$5 \text{ mA} < I_{\text{Q}} < 200 \text{ mA}$ $6 \text{ V} < V_{\text{I}} < 40 \text{ V}$
Output voltage V85-Version	$V_{Q}$	8.16	8.5	8.84	V	$5 \text{ mA} < I_{\text{Q}} < 400 \text{ mA}$ $9.5 \text{ V} < V_{\text{I}} < 28 \text{ V}$
Output voltage V85-Version	$V_{Q}$	8.16	8.5	8.84	V	$5 \text{ mA} < I_{\text{Q}} < 200 \text{ mA}$ $9.5 \text{ V} < V_{\text{I}} < 40 \text{ V}$
Output voltage V10-Version	$V_{Q}$	9.6	10	10.4	V	5 mA < $I_{\rm Q}$ < 400 mA 11 V < $V_{\rm I}$ < 28 V
Output voltage V10-Version	$V_{Q}$	9.6	10	10.4	V	5 mA < $I_{\rm Q}$ < 200 mA 11 V < $V_{\rm I}$ < 40 V
Output current limitation <sup>1)</sup>	$I_{Q}$	400	600	_	mA	_
Current consumption; $I_q = I_l - I_Q$	$I_{q}$	_	100	220	μΑ	$I_{\rm Q}$ = 1 mA
Current consumption; $I_q = I_l - I_Q$	$I_{q}$	_	8 20	15 30	mA mA	$I_{\rm Q}$ = 250 mA $I_{\rm Q}$ = 400 mA
Drop voltage <sup>1)</sup>	$V_{dr}$	_	250	500	mV	$I_{\rm Q}$ = 250 mA $V_{\rm dr}$ = $V_{\rm I}$ - $V_{\rm Q}$
Load regulation	$\Delta V_{Q}$	_	20	50	mV	$I_{\rm Q}$ = 5 mA to 400 mA
Line regulation	$\Delta V_{Q}$	_	10	25	mV	$\Delta V_{\rm I}$ = 12 V to 32 V $I_{\rm Q}$ = 5 mA
Power supply ripple rejection	PSRR	_	60	_	dB	$f_{\rm r}$ = 100 Hz; $V_{\rm r}$ = 0.5 Vpp
Temperature output voltage drift	$\mathrm{d}V_{\mathrm{Q}}/\mathrm{d}T$	_	0.5	_	mV/K	_

<sup>1)</sup> Measured when the output voltage  $V_{\rm Q}$  has dropped 100 mV from the nominal value obtained at  $V_{\rm I}$  = 13.5 V.

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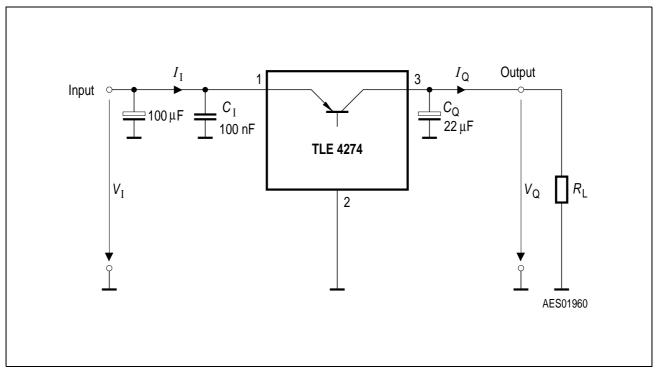


Figure 3 Measuring Circuit

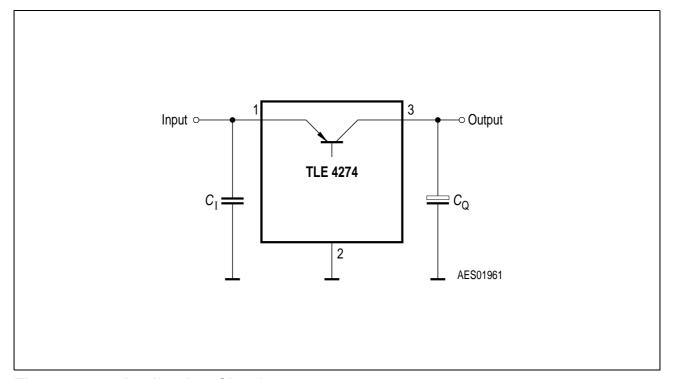


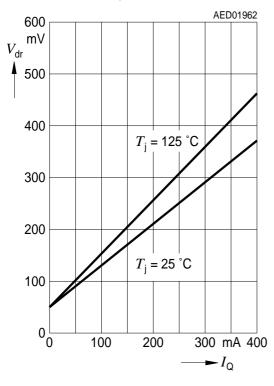
Figure 4 Application Circuit

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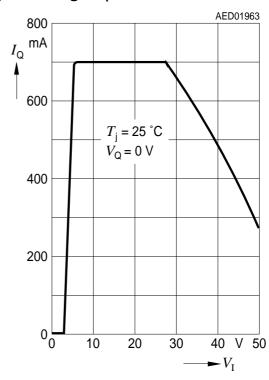


#### Typical Performance Characteristics (V50, V85 and V10)

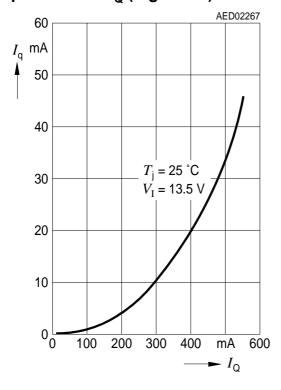
### Drop Voltage $V_{\mathrm{dr}}$ versus Output Current $I_{\mathrm{Q}}$



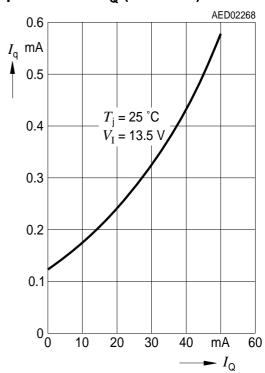
### Output Current $I_{\mathsf{Q}}$ versus Input Voltage $V_{\mathsf{I}}$



# Current Consumption $I_{\rm q}$ versus Output Current $I_{\rm Q}$ (high load)



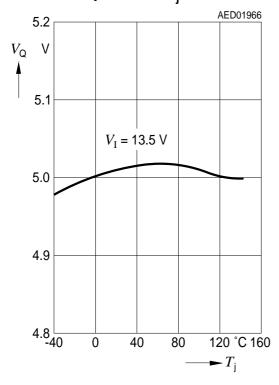
# Current Consumption $I_{\rm q}$ versus Output Current $I_{\rm Q}$ (low load)



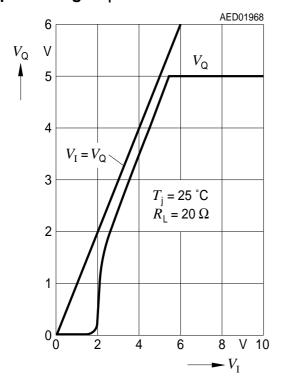


#### **Typical Performance Characteristics (V50)**

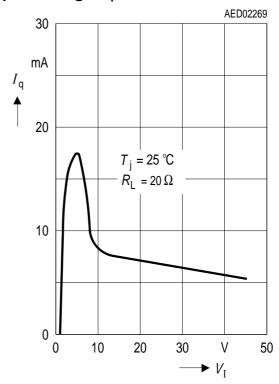
### Output Voltage $V_{Q}$ versus Junction Temperature $T_{i}$



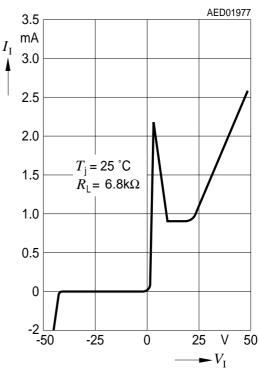
## Output Voltage $V_{\rm Q}$ versus Input Voltage $V_{\rm I}$



## Current Consumption $I_{\rm q}$ versus Input Voltage $V_{\rm I}$



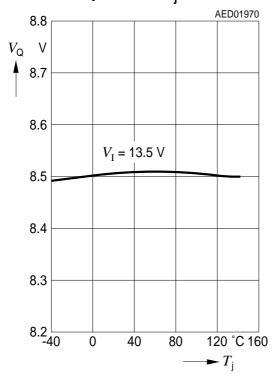
## Input Current $I_{\rm I}$ versus Input Voltage $V_{\rm I}$



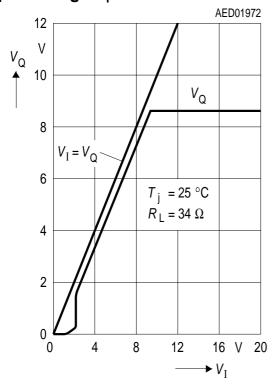


#### **Typical Performance Characteristics for V85**

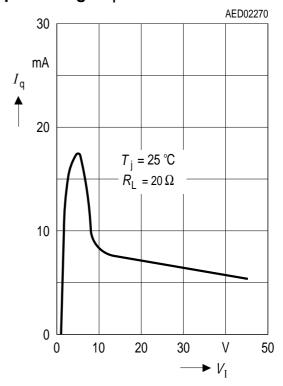
### Output Voltage $V_{Q}$ versus Junction Temperature $T_{i}$



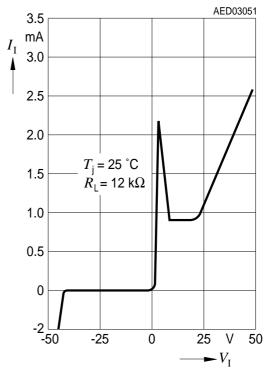
# Output Voltage $V_{\rm Q}$ versus Input Voltage $V_{\rm I}$



## Current Consumption $I_{\rm q}$ versus Input Voltage $V_{\rm I}$



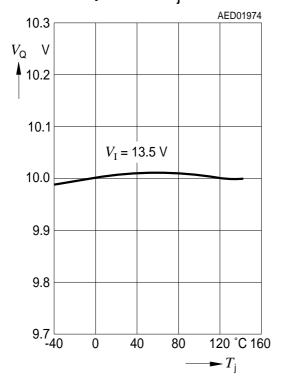
## Input Current $I_{\rm I}$ versus Input Voltage $V_{\rm I}$



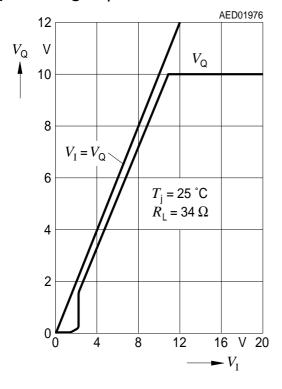


#### **Typical Performance Characteristics for V10**

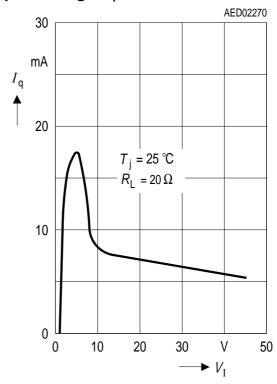
### Output Voltage $V_{Q}$ versus Junction Temperature $T_{i}$



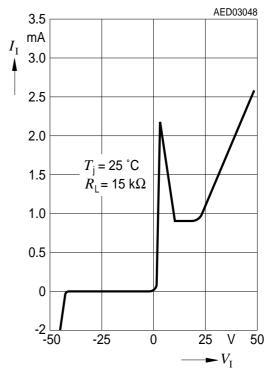
# Output Voltage $V_{\rm Q}$ versus Input Voltage $V_{\rm I}$



## Current Consumption $I_{\rm q}$ versus Input Voltage $V_{\rm l}$



## Input Current $I_{\rm I}$ versus Input Voltage $V_{\rm I}$





#### **Package Outlines**

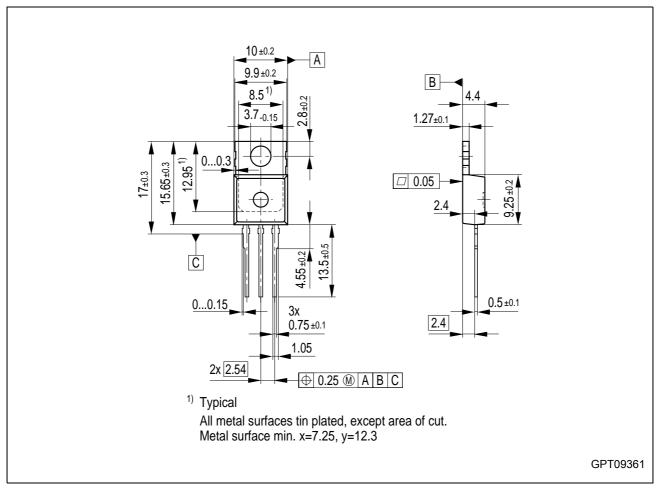


Figure 5 PG-TO220-3-1 (Plastic Transistor Single Outline)

#### **Green Product (RoHS-Compliant)**

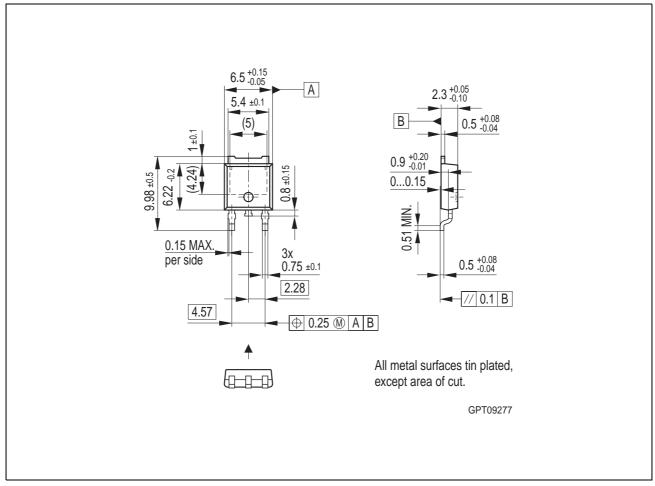
To meet the world-wide customer requirements for environmentally friendly products and to be compliant with government regulations the device is available as a green product. Green products are RoHS-Compliant (i.e Pb-free finish on leads and suitable for Pb-free soldering according to IPC/JEDEC J-STD-020).

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SMD = Surface Mounted Device

Dimensions in mm





**Figure 6 PG-TO252-3-11** (Plastic Transistor Single Outline)

#### **Green Product (RoHS-Compliant)**

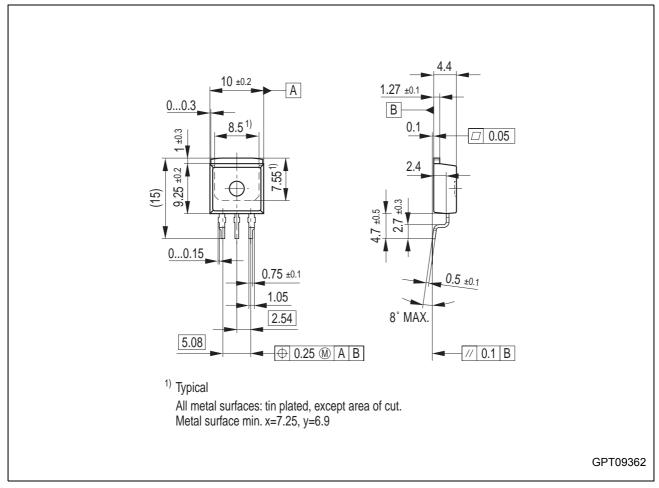
To meet the world-wide customer requirements for environmentally friendly products and to be compliant with government regulations the device is available as a green product. Green products are RoHS-Compliant (i.e Pb-free finish on leads and suitable for Pb-free soldering according to IPC/JEDEC J-STD-020).

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SMD = Surface Mounted Device

Dimensions in mm





**Figure 7 PG-TO263-3-1** (Plastic Transistor Single Outline)

#### **Green Product (RoHS-Compliant)**

To meet the world-wide customer requirements for environmentally friendly products and to be compliant with government regulations the device is available as a green product. Green products are RoHS-Compliant (i.e Pb-free finish on leads and suitable for Pb-free soldering according to IPC/JEDEC J-STD-020).

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SMD = Surface Mounted Device

Dimensions in mm



### **TLE 4274**

Revision Histor	y: 2007-01-23	Rev. 1.6		
Previous Version	n: 1.5			
Page	Subjects (major changes since last	revision)		
general	Updated Infineon logo			
#1	Added "AEC" and "Green" logo			
#1	Added "Green Product" and "AEC qua	alified" to the feature list		
#1	Updated Package Names to "PG-xxx"			
general	Removed leadframe variant "P-TO-25	2-1"		
#12, #13, #14	Added "Green Product" remark			
#16	Disclaimer Update			

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